Drawing No.: RPGW-K-HTS-0002 /2

Date: 2025.1.21

Data sheet

Title: FIXED THICK FILM CHIP RESISTORS; RECTANGULAR TYPE AND

HIGH POWER · ANTI SURGE ANTI-SULFRATION

Style: RPGW16,20,32,35

AEC-Q200 qualified

RoHS COMPLIANCE ITEM Halogen and Antimony Free

Note: •Stock conditions

Temperature: $+5^{\circ}\text{C} \sim +35^{\circ}\text{C}$ Relative humidity: $25\% \sim 75\%$

The period of guarantee: Within 2 year from shipmen t by the company.

Solderability shall be satisfied.

- Product specification contained in this data sheet are subject to change at any time without notice
- If you have any questions or a Purchasing Specification for any quality agreement is necessary, please contact our sales staff.



Hokkaido Research Center Approval by: T. Sannomiya Drawing by: M. Shibuya

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Style

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1. Scope

1.1 This data sheet covers the detail requirements for fixed thick film chip resistors; rectangular type & high power · anti surge anti sulfration, style of RPGW16,20,32,35.

1.2 Applicable documents

JIS C 5201-1: 2011, IEC60115-1: 2008, AEC-Q200 Rev.D

2. Classification

Type designation shall be the following form.

(Example)

RPGW	32	K	123	J	TP
1	2	3	4	5	6
Style	e				

- 1 Fixed thick film chip resistors; rectangular type & high power · anti surge anti-sulfration. ·
- 2 Rated dissipation and / or dimension
- 3 Temperature coefficient of resistance

K	±100×10 ⁻⁶ / °C
–(Dash)	Standard

4 Rated resistance

123	E24 Series, 3 digit,	Ex. 123-> 12kΩ,
1000	E96 Series, 4 digit,	Ex. 1000>100Ω
		1022> 10.2kΩ

5 Tolerance on rated resistance

D	±0.5%
F	±1%
J	±5%

6 Packaging form

TP	Paper taping	
TE	Embossed taping	

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3. Rating

3.1 The ratings shall be in accordance with Table-1.

Table-1

Style	Rated dissipation (W)		ure coefficient of nce (10 ⁶ / °C)	Rated resistance range (Ω)	Preferred number series for resistors	Tolerance on rated resistance
		K	±100	10~1M	E24, 96	D(±0.5%),
RPGW16	0.33	Standard	±200	1.0~9.76	L24, 90	F(±1%)
REGIVIO	0.55	K	±100	10~1M	E24	1/+50/>
		Standard	±200	1.0~9.1	E2 4	J(±5%)
		K	±100	10~1M	E24, 96	D(±0.5%),
RPGW20	0.5	Standard	±200	1.0~9.76	E24, 90	F(±1%)
KPGVV20		K	±100	10~1M	E24	J(±5%)
		Standard	±200	1.0~9.1		
	20 000	K	±100	10~1M	E34 06	D(±0.5%),
DDOM/00		Standard	±200	1.0~9.76	E24, 96	F(±1%)
RPGW32	0.66	K	±100	10~1M	E24	1/+50/>
		Standard	±200	1.0~9.1	E2 4	J(±5%)
	0.75	K	±100	10~1M	E24, 96	D(±0.5%),
DDOMOE		Standard	±200	1.0~9.76		F(±1%)
RPGW35		K	±100	10~1M	E24	1/+50/>
		Standard	±200	1.0~9.1		J(±5%)

Style	Limiting element voltage (V)	Insulation voltage (V)	Category temperature range(°C)
RPGW16	150	150	
RPGW20			FF. 1155
RPGW32	200	500	<i>–</i> 55∼+155
RPGW35			

3.2 Climatic category

55/155/56 Lower category temperature $-55\,^{\circ}\text{C}$

Upper category temperature +155 °C

Duration of the damp heat, steady state test 56days

3.3 Stability class

2% Limits for change of resistance:

-for long-term tests $\pm (2\% + 0.1\Omega)$

-for short-term tests $\pm (0.5\% + 0.05\Omega)$

3.4 Derating

The derated values of dissipation at temperature in excess of 70 °C shall be as indicated by the following curve.

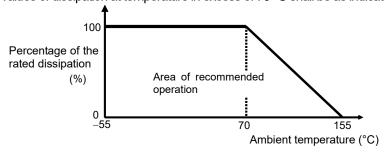


Figure-1 Derating curve

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3.5 Rated voltage

d.c.or a.c.r.m.s.voltage calculated from the square root of the product of the rated resistance and the rated dissipation.

$$E = \sqrt{P \cdot R}$$

E: Rated voltage (V)

P: Rated dissipation (W)

R: Rated resistance (Ω)

Limiting element voltage can only be applied to resistors when the resistance value is equal to or higher than the critical resistance value.

At high value of resistance, the rated voltage may not be applicable.

4. Packaging form

The standard packaging form shall be in accordance with Table-2.

Table-2

Symbol	Packaging form		Standard packaging quantity / units	Application
TP	Paper taping	8mm width, 4mm pitches	5,000 pcs.	RPGW 16,20,32
TE	Embossed taping	8mm width, 4mm pitches	4,000 pcs.	RPGW 35

5. Dimensions

5.1 The resistor shall be of the design and physical dimensions in accordance with Figure-2 and Table-3.

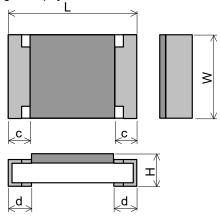


Figure-2

	Unit: mm				
Style	L	W	Н	С	d
RPGW16	1.6±0.1	0.8 +0.15 +0.05	0.45±0.10	0.25±0.10	0.3±0.1
RPGW20	2.0±0.1	1.25±0.10	0.55±0.10	0.3±0.2	0.4±0.2
RPGW32	3.1±0.1	1.6±0.15	0.55±0.10	0.4±0.25	0.5±0.25
RPGW35	3.1±0.15	2.5±0.15	0.55±0.15	0.4±0.25	0.5±0.25

5.2 Net weight (Reference)

<u> </u>	
Style	Net weight(mg)
RPGW16	2
RPGW20	5
RPGW32	9
RPGW35	16



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6. Marking

The Rated resistance shall be marked in 3 digits (E24) or 4 digits (E96) and marked on over coat side.

• E24 series: 3 digits, E96 series: 4 digits

In case of the resistance value that E96 overlaps with E24, It is marked by either.

The Rated resistance of RPGW16 should not be marked in 4 digits(E96).

Marking example	Contents	Application
123	12×10 ³ $[\Omega] \rightarrow$ 12 $[k\Omega]$	RPGW 16,20,32,35
2R2	2.2 [Ω]	Less than 10Ω of RPGW 16,20,32,35
5623	$562 \times 10^3 [\Omega] \rightarrow 562 [k\Omega]$	RPGW 20,32,35
12R7	12.7 [Ω]	RPGW 20,32,35

KAMAYA OHM

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7. Performance

7.1 The standard condition for tests shall be in accordance with Sub-clause 4.2, JIS C 5201–1: 2011.

7.2 The performance shall be satisfied in Table-4.

Table-4(1)

		Iable—4(1)	
No	Test items	Condition of test	Performance requirements
1	High temperature exposure AEC Q200 - No.3	MIL-STD-202 Method 108 Ambient temperature:155±2°C, Condition: Without load, Duration: 1,000 +48 h Interval measurements: 250 h and 500 h	Δ R/R: Within \pm (1%+0.05 Ω) No visible damage
2	Temperature cycling AEC Q200 - No.4	JESD22 Method JA-104 Temperature: -55±3°C / 125±2°C, Dwell time: 30min maximum at each temp. Transition time: 1 min. max. Number of cycles: 1,000 cycles. Interval measurements: 250 cy and 500 cy	Δ R/R: Within $\pm (0.5\% + 0.05\Omega)$ No visible damage
3	Bias humidity AEC Q200 – No.7	MIL-STD-202 Method 103 Condition: 85°C & 85% R.H. Test power: 10% of rated power shall be applied for continuously. Duration: 1,000 +48 / 0 h Interval measurements: 250 h and 500 h	Δ R/R: Within \pm (1%+0.05 Ω) No visible damage
4	Operational life AEC Q200 – No.8	MIL-STD-202 Method 108 Ambient temperature: 125±2°C The applied voltage shall be the voltage to be calculated at 35% of rated dissipation or the limiting element voltage whichever is the smaller. Condition: The voltage shall be applied for continuously. Duration: 1,000 +48	Δ R/R: Within ±(1%+0.05Ω) No visible damage
5	External Visual AEC Q200 – No.9	MIL-STD-883 Method 2009	Inspect device construction, marking and workmanship.
6	Dimensions AEC Q200 – No.10	JESD22 Method JB-100	As in Table–3
7	Resistance to Solvents AEC Q200 – No.12	MIL-STD-202 Method 215 Solvent: 2-propanol at 25°C Immersion time: 3 min Brush: 10 times brushing Immersion and brush cycle: 3cycle	Δ R/R: Within \pm (1%+0.05 Ω) No visible damage
8	Mechanical Shock AEC Q200 – No.13	MIL-STD-202 Method 213 Waveform: half sine, Peak value100G, Normal duration 6ms Condition: XX'YY'ZZ', 18times total	Δ R/R: Within $\pm (0.5\% + 0.05\Omega)$ No visible damage

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Table-4(2)

	Table-4(2)								
No	Test items	Condition of test	Performance requirements						
9	Vibration	MIL-STD-202 Method 204	Δ R/R: Within \pm (0.5%+0.05 Ω)						
	AEC Q200 – No.14	Peak acceleration and Sweep time: 5 g's for 20	No visible damage						
		min , Frequency 10Hz to 2000Hz,							
		Condition: 12 cycles each of 3 orientations							
10	Resistance to soldering heat	MIL-STD-202 Method 210	Resistor: Δ R/R: Within \pm (0.5%+0.05 Ω)						
	AEC Q200 - No.15	Solder bath temp: 260±5°C	Chip jumper: $50m\Omega$ max.						
		Immersed time: 10±1s	No visible damage						
11	ESD test	AEC-Q200-002	Δ R/R: Within ±(1%+0.05 Ω)						
	AEC Q200 – No.17	Human body model, 2 Kohm, 150 pF,	No visible damage						
		Test voltage: RPGW20,32,35 3000V							
	RPGW16 2000V								
12	Solderability	J-STD-002	The surface of terminal immersed						
	AEC Q200 – No.18	a) Bake the sample for 155 °C dwell time 4h /	shall be min. of 95% covered with a						
		solder dipping 235°C/5s.	new coating of solder.						
		Solder: Sn96.5-Ag3-Cu0.5							
		b) Category 3, Solder dipping 215°C/5s. Solder: Sn63Pb37							
13	Electrical Characterization	c) Category 3, Solder dipping 260°C/30s. 1. D.C. Resistance	The resistance value shall						
13	AEC Q200 - No.19	Temperature Coefficient of Resistance	correspond with the rated						
	ALC Q200 - 110.19	-55 °C / +20°C	resistance taking into account the						
		+20 °C / +155°C	specified tolerance.						
		120 07 1100 0	2. As in Table–1						
14	Flammability	UL-94	V-0 or V-1 are acceptable						
	AEC Q200 – No.20		v o or v raise acceptable						
15	Bending strength	AEC-Q200-005	Δ R/R: Within \pm (0.5%+0.05 Ω)						
	AEC Q200 – No.21	Bending value2mm	No visible damage						
		Holding time: 60sec.	S						
16	Adhesion	AEC-Q200-006	Δ R/R: Within \pm (0.5%+0.05 Ω)						
	AEC Q200 – No.22	Pressurizing force:	No visible damage						
		RPGW20,32,35 17.7N	-						
		RPGW16 10N							
		Test time: 60±1s.							
17	Flame retardance	AEC-Q200-001	The following FAILURE CRITERIA						
	AEC Q200 – No.24	Test conditions: 9VDC to 32VDC Each 1h	does not occur.						
		This test applies to rated voltages of 32V and	FAILURE CRITERIA						
		above.	- Electrically open						
			a) A flame over 3.0 seconds duration						
			b) An explosion						
			c) A temperature above 350°C						
10	Lippoid Cultury or ar to at	ACTM DOOD	sustained for over 10 s						
18	Humid Sulfur vapor test	ASTM B809 Recognit: Sulfur (Saturated vapor)	$\Delta R \leq \pm (1\% + 0.05\Omega)$						
	(FOS)	Reagent: Sulfur (Saturated vapor)							
		Test temp.: 60°C							
		Relative humidity: 95%RH							
		Test period: 1000h							

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8. Taping

- 8.1 Applicable documents JIS C 0806-3: 2014, EIAJ ET-7200C: 2010
- 8.2 Taping dimensions
- 8.2.1 Taping dimensions shall be in accordance with Figure-3 and Table-5.

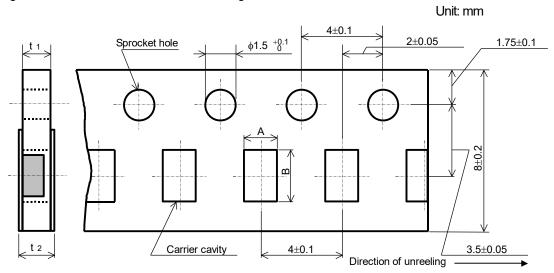


Figure-3

	Unit: mm			
Style	Α	В	t ₁	t 2
RPGW16	1.15±0.15	1.9±0.2	0.6±0.1	0.8max.
RPGW20	1.65±0.15	2.5±0.2	0.8±0.1	1.0max.
RPGW32	2.00±0.15	3.6±0.2	0.8±0.1	1.0max.

8.2.2 Embossed taping dimensions shall be in accordance with Figure-4 and Table-6.

Unit: mm

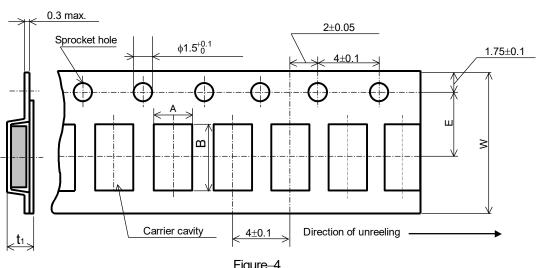


Figure-4

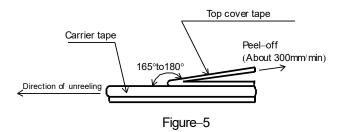
		Table	- -6	Unit: mm	
Style	Α	В	W	E	t 1
RPGW35	2.85±0.20	3.5±0.2	8.0±0.3	3.5±0.05	1.0±0.2

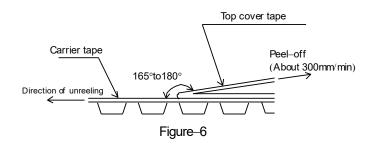
Title: FIXED THICK FILM CHIP RESISTORS; RECTANGULAR TYPE AND HIGH POWER: ANTI SURGE ANTI-SUI FRATION REGW16 20 32 3

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- 1). The cover tapes shall not cover the sprocket holes.
- 2). Tapes in adjacent layers shall not stick together in the packing.
- 3). Components shall not stick to the carrier tape or to the cover tape.
- 4). Pitch tolerance over any 10 pitches ±0.2mm.
- 5). The peel strength of the top cover tape shall be with in 0.1N to 0.5N on the test method as shown in the following RPGW16,20,32:Figure-4,RPGW35:Figure-5.
- 6). When the tape is bent with the minimum radius for 25 mm, the tape shall not be damaged and the components shall maintain their position and orientation in the tape.
- 7). In no case shall there be two or more consecutive components missing.

 The maximum number of missing components shall be one or 0.1%, whichever is greater.
- 8). The resistors shall be faced to upward at the over coating side in the carrier cavity.





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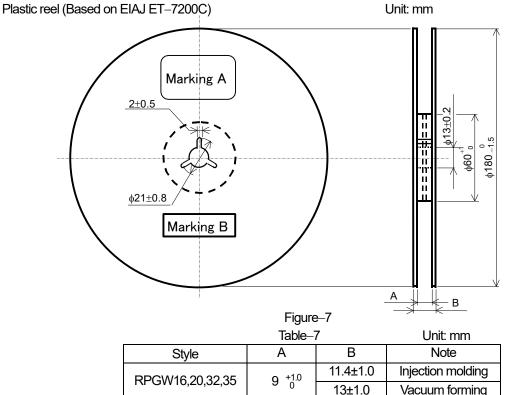
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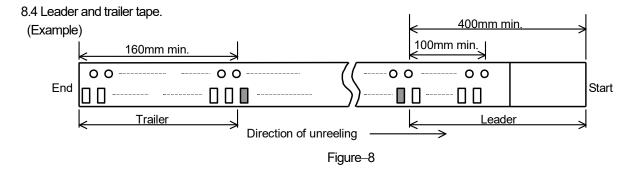
Title: FIXED THICK FILM CHIP RESISTORS; RECTANGULAR TYPE AND HIGH POWER · ANTI SURGE ANTI-SULFRATION RPGW16,20,32,35

8.3 Reel dimension

Reel dimensions shall be in accordance with the following Figure-7 and Table-7.



Note: Marking label shall be marked on a place of Marking A or two place of marking A and B.



9. Marking on package

The label of a minimum package shall be legibly marked with follows.

9.1 Marking A

(1) Classification

(Style, Temperature coefficient of resistance, Rated resistance, Tolerance on rated resistance, Packaging form)

- (2) Quantity (3) Lot number (4) Manufacturer's name or trade mark (5) Others
- 9.2 Marking B (KAMAYA control label)